NSN 5962-01-328-7217

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View Online at https://aerobasegroup.com/nsn/5962-01-328-7217

Overal	II Leng	th:

Between 0.875 inches and 0.925 inches

Overall Height:

Between 0.265 inches and 0.360 inches

Body Length:

Between 0.875 inches and 0.925 inches

Body Width:

Between 0.280 inches and 0.310 inches

Body Height:

Between 0.080 inches and 0.185 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

High speed and high reliability and low current and bipolar

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Current Rating Per Characteristic:

250.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

5.00 input picofarads and 8.00 output picofarads

Time Rating Per Chacteristic:

70.00 nanoseconds af output megawatts

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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